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Fairchild Semiconductor BC847BS

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Datasheet of BC847BS - TRANS 2NPN 45V 0.1A SC70-6

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June 2007

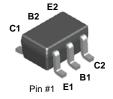
BC847BS

NPN Multi-chip General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 200 mA. Sourced from Process 07.

Dual NPN Signal Transister

SC70-6 Mark: .1F



4 are interchangeable. Units inside the carrier can be of either orientation and will not affect the functionality of the device.

Absolute Maximum Ratings * Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	50	V
V _{CES}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current (DC)	100	mA
$T_{J_i}T_{STG}$	Junction Temperature and Storage Temperature	-55 ~ + 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

Thermal Characteristics * T_a = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
PD	Total Device Dissipation	210	mW
	Derate above 25°C	1.6	mW/°C
$R \oplus JA$	Thermal Resistance, Junction to Ambient	625	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.



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Electrical Characteristics * T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	MIN	MAX	Units
Off Characteristics					
V _(BR) CBO	Collector-Emitter Breakdown Voltage	Ic = 10 μA, Iε = 0	50		V
V _(BR) CES	Collector-Base Breakdown Voltage	Ic = 10 μA, Iε = 0	50		V
V _(BR) CEO	Collector-Base Breakdown Voltage	Ic = 10 mA, I _B = 0	45		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	6.0		V
Ісво	Collector-Cutoff Current	Vcb = 30 V, IE = 0 Vcb = 30 V, IE = 0, TA = 150°C		15 5.0	nA μA

On Characteristics

hfe	DC Current Gain	Ic = 2.0 mA, VcE = 5.0 V	200	450	
VcE(sat)	Collector-Emitter Saturation Voltage *	Ic = 10 mA, I _B = 0.5 mA Ic = 100 mA, I _B = 5.0 mA		0.25 0.65	V V
V _{BE} (on)	S S	Ic = 2.0 mA, VcE = 5.0 V Ic = 10 mA, VcE = 5.0 V	0.58	0.7 0.77	V V

^{*} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.



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Datasheet Identification	Product Status	Definition
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Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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